

STGF30NC60S STGP30NC60S, STGWF30NC60S

30 A, 600 V, fast IGBT

Features

- Optimized performance for medium operating frequencies up to 5 kHz in hard switching
- Low on-voltage drop (V_{CE(sat)})
- High current capability

Application

Motor drive

Description

This device utilizes the advanced PowerMESH™ process resulting in an excellent trade-off between switching performance and low on-state behavior.

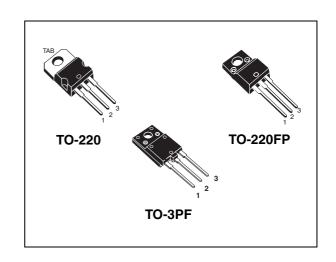


Figure 1. Internal schematic diagram

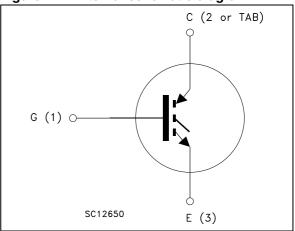


Table 1. Device summary

Order codes	Marking	Package	Packaging
STGF30NC60S	GF30NC60S	TO-220FP	
STGP30NC60S	GP30NC60S	TO-220	Tube
STGWF30NC60S	GWF30NC60S	TO-3PF	

Contents

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3	Test circuits
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1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter		Value		Unit
Symbol	Farameter	TO-220	TO-220FP	TO-3PF	Unit
V _{CES}	Collector-emitter voltage (V _{GE} = 0)		600		V
I _C ⁽¹⁾	Continuous collector current at T _C = 25 °C	55	22	35	Α
I _C ⁽¹⁾	Continuous collector current at T _C = 100 °C	35	11	18	Α
I _{CL} ⁽²⁾	Turn-off latching current		150		Α
I _{CP} (3)	Pulsed collector current		150		Α
V_{GE}	Gate-emitter voltage		±20		٧
V _{ISO}	Insulation withstand voltage (RMS) from all three leads to external heat sink (t=1 s; T_C =25 °C)		250	00	V
P _{TOT}	Total dissipation at $T_C = 25$ °C 175 40 79		79	W	
T _j	Operating junction temperature		- 55 to 150		°C

1. Calculated according to the iterative formula:

$$I_{C}(T_{C}) = \frac{T_{j(max)} - T_{C}}{R_{thj-c} \times V_{CE(sat)(max)}(T_{j(max)}, I_{C}(T_{C}))}$$

- 2. V_{clamp} = 80%,(V_{CES}), T_j =150 °C, R_G = 10 Ω , V_{GE} = 15 V
- 3. Pulse width limited by maximum junction temperature and turn-off within RBSOA

Table 3. Thermal data

Symbol Parameter			Unit		
Symbol	raiailletei	TO-220	TO-220FP	TO-3PF	Oilit
R _{thj-case}	Thermal resistance junction-case	0.7	3.1	1.58	°C/W
R _{thj-amb}	Thermal resistance junction-ambient	6	2.5	50	°C/W

2 Electrical characteristics

(T_J= 25 °C unless otherwise specified)

Table 4. Static

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)CES}	Collector-emitter breakdown voltage $(V_{GE} = 0)$	I _C = 1 mA	600			V
V _{CE(sat)}	Collector-emitter saturation voltage	V _{GE} = 15 V, I _C = 20 A V _{GE} = 15 V, I _C = 20 A,T _J =150 °C		1.5 1.4	1.9	V V
V _{GE(th)}	Gate threshold voltage	$V_{CE} = V_{GE}, I_{C} = 250 \mu A$	3.75		5.75	V
I _{CES}	Collector cut-off current (V _{GE} = 0)	V _{CE} = 600 V V _{CE} = 600 V, T _J = 150 °C			150 1	μA mA
I _{GES}	Gate-emitter cut-off current (V _{CE} = 0)	V _{GE} = ±20 V			±100	nA
9 _{fs} ⁽¹⁾	Forward transconductance	$V_{CE} = 15 V_{,} I_{C} = 20 A$		10		S

^{1.} Pulsed: pulse duration = 300 μs, duty cycle 1.5%

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
C _{ies} C _{oes} C _{res}	Input capacitance Output capacitance Reverse transfer capacitance	$V_{CE} = 25 \text{ V, f} = 1 \text{ MHz, V}_{GE} = 0$	-	2200 185 48.5	-	pF pF pF
Q _g Q _{ge} Q _{gc}	Total gate charge Gate-emitter charge Gate-collector charge	$V_{CE} = 480 \text{ V, } I_{C} = 20 \text{ A,}$ $V_{GE} = 15 \text{ V}$ Figure 19		96 14 44.5	1	nC nC nC

Table 6. Switching on/off (inductive load)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t _{d(on)} t _r (di/dt) _{on}	Turn-on delay time Current rise time Turn-on current slope	V_{CC} = 480 V, I_{C} = 20 A R_{G} = 10 Ω V _{GE} = 15 V Figure 18	-	21.5 8.5 2280	-	ns ns A/µs
t _{d(on)} t _r (di/dt) _{on}	Turn-on delay time Current rise time Turn-on current slope	$V_{CC} = 480 \text{ V, } I_{C} = 20 \text{ A}$ $R_{G} = 10 \Omega \text{ V}_{GE} = 15 \text{ V,}$ $T_{J} = 125 ^{\circ}\text{C}$ Figure 18	-	20.5 9.5 2150	-	ns ns A/µs
$t_r(V_{off})$ $t_d(_{off})$ t_f	Off voltage rise time Turn-off delay time Current fall time	$V_{cc} = 480 \text{ V}, I_{C} = 20 \text{ A},$ $R_{GE} = 10 \Omega, V_{GE} = 15 \text{ V}$ Figure 18	-	85 180 200	-	ns ns ns
t _r (V _{off}) t _d (_{off}) t _f	Off voltage rise time Turn-off delay time Current fall time	$V_{cc} = 480 \text{ V}, I_{C} = 20 \text{ A},$ $R_{GE} = 10 \Omega, V_{GE} = 15 \text{ V}$ $T_{J} = 125 \text{ °C}$ Figure 18	-	155 260 295	-	ns ns ns

Table 7. Switching energy (inductive load)

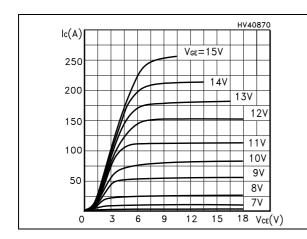
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Eon E _{off} ⁽¹⁾ E _{ts}	Turn-on switching losses Turn-off switching losses Total switching losses	V_{CC} = 480 V, I_{C} = 20 A R_{G} = 10 Ω V_{GE} = 15 V, Figure 18	-	300 1275 1575		μJ μJ μJ
Eon E _{off} ⁽¹⁾ E _{ts}	Turn-on switching losses Turn-off switching losses Total switching losses	$V_{CC} = 480 \text{ V}, I_{C} = 20 \text{ A}$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V},$ $T_{J} = 125 ^{\circ}\text{C}$ Figure 18	-	430 1965 2395	1	μJ μJ μJ

^{1.} Turn-off losses include also the tail of the collector current.

2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

Figure 3. Transfer characteristics



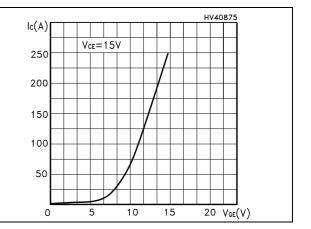
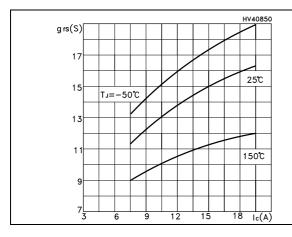


Figure 4. Transconductance

Figure 5. Collector-emitter on voltage vs temperature



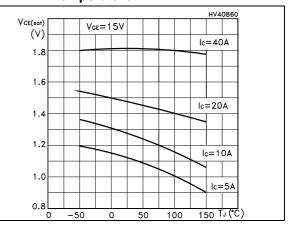
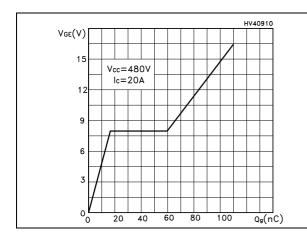
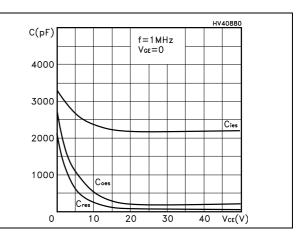


Figure 6. Gate charge vs gate-source voltage Figure 7. Capacitance variations





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Figure 8. Normalized gate threshold voltage Figure 9. Collector-emitter on voltage vs vs temperature collector current

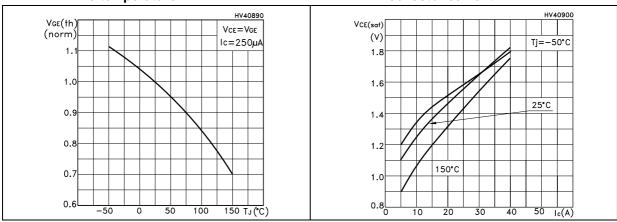


Figure 10. Normalized breakdown voltage vs Figure 11. Switching losses vs temperature temperature

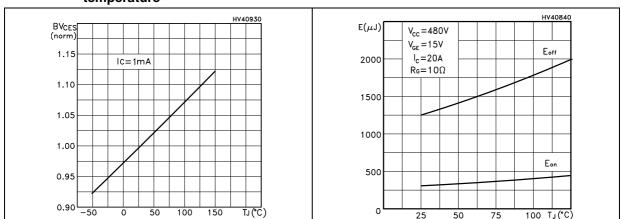


Figure 12. Switching losses vs gate resistance Figure 13. Switching losses vs collector current

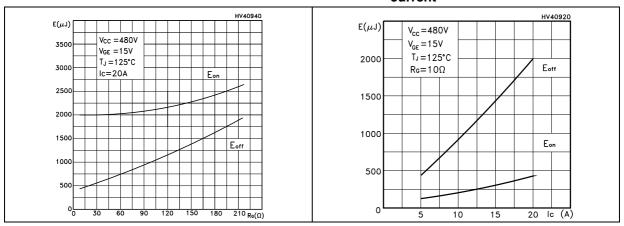


Figure 14. Thermal Impedance

Figure 15. Turn-off SOA

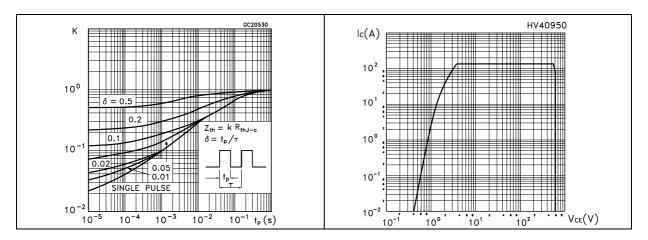
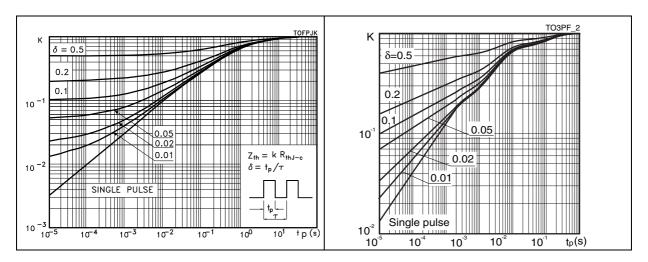


Figure 16. Thermal Impedance for TO-220FP Figure 17. Thermal Impedance for TO-3PF



3 Test circuits

Figure 18. Test circuit for inductive load switching

Figure 19. Gate charge test circuit

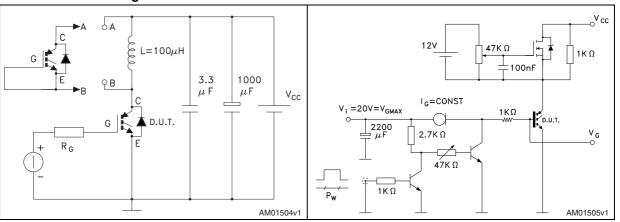
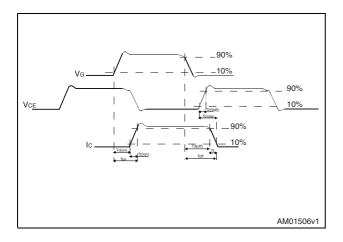


Figure 20. Switching waveforms



4 Package mechanical data

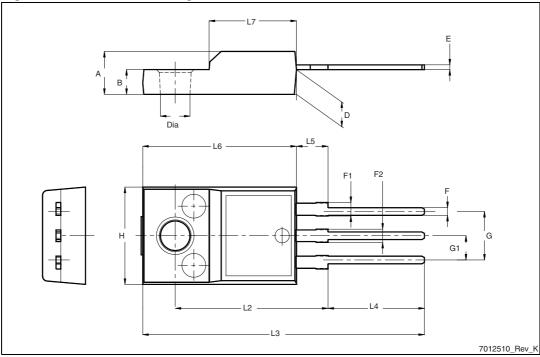
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Table 8. TO-220FP mechanical data

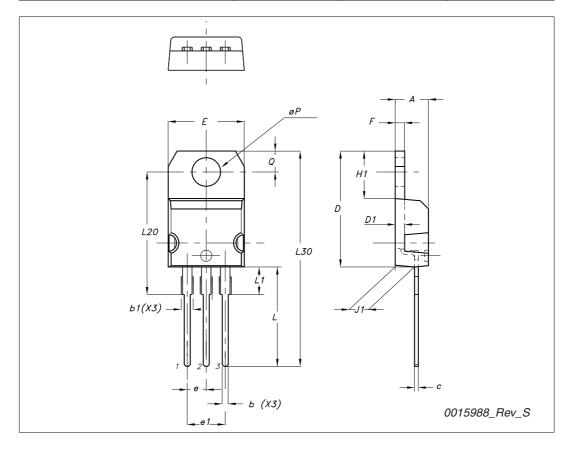
Dim		mm	
Dim.	Min.	Тур.	Max.
Α	4.4		4.6
В	2.5		2.7
D	2.5		2.75
Е	0.45		0.7
F	0.75		1
F1	1.15		1.70
F2	1.15		1.70
G	4.95		5.2
G1	2.4		2.7
Н	10		10.4
L2		16	
L3	28.6		30.6
L4	9.8		10.6
L5	2.9		3.6
L6	15.9		16.4
L7	9		9.3
Dia	3		3.2

Figure 21. TO-220FP drawing



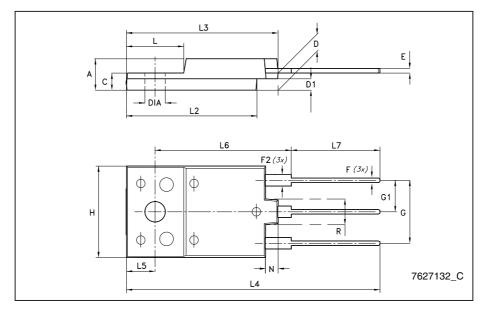
TO-220 type A mechanical data

Di		mm	
Dim	Min	Тур	Max
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
С	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
е	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95



TO-3PF mechanical da

DIM.		mm.	
DIW.	min.	typ	max.
Α	5.30		5.70
С	2.80		3.20
D	3.10		3.50
D1	1.80		2.20
Е	0.80		1.10
F	0.65		0.95
F2	1.80		2.20
G	10.30		11.50
G1		5.45	
Н	15.30		15.70
L	9.80	10	10.20
L2	22.80		23.20
L3	26.30		26.70
L4	43.20		44.40
L5	4.30		4.70
L6	24.30		24.70
L7	14.60		15
N	1.80		2.20
R	3.80		4.20
Dia	3.40		3.80



5 Revision history

Table 9. Document revision history

Date	Revision	Changes
02-Jul-2007	1	Initial release
20-Nov-2007	2	Document status promoted from preliminary data to datasheet
04-May-2009	3	Added new package, mechanical data: TO-220FP
30-Jun-2010	4	Added new package, mechanical data: TO-3PF
11-Nov-2010	5	Updated data for TO-3PF in <i>Table 2</i> and <i>Table 3</i>Modified <i>Figure 17</i>

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